



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Fastow et al.

Serial No.: 10/658,936

Filed: September 9, 2003

For: FLASH MEMORY WITH  
HIGH-K DIELECTRIC  
MATERIAL BETWEEN  
SUBSTRATE AND GATE

Examiner: NGUYEN, D.

Art Unit: 2818

Confirmation No.: 3102

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

RESPONSE TO OFFICE ACTION

Dear Sir:

In response to the Office Action mailed January 23, 2007, please consider the following remarks. The claims are presented beginning on page 2 of this response. Remarks begin on page 6.